
	<h2>SI7501DN-T1-E3</h2>
	<p>Hersteller-Teilenummer: SI7501DN-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N/P-CH 30V 5.4A 1212-8</p> <p>Datenblätter:  SI7501DN-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 1056 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI7501DN-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N/P-CH 30V 5.4A 1212-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	1056 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	1.6W
Verpackung / Gehäuse	PowerPAK® 1212-8 Dual
Supplier Device-Gehäuse	PowerPAK® 1212-8 Dual
Typ FET	N and P-Channel, Common Drain
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	5.4A, 4.5A
Rds On (Max) @ Id, Vgs	35 mOhm @ 7.7A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	14nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Original-Reel®



















































SI7501DN-T1-E3 ist neu im Original, Suche SI7501DN-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7501DN-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7501DN-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7495DP-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 12V 13A PPAK SO-8</p>	 <p>SI7501DN-T1-GE3 Vishay / Siliconix MOSFET N/P-CH 30V 5.4A 1212-8</p>	 <p>SI7530DP SI SI7530DP SI</p>	 <p>SI7501DN-T1 Vishay Precision Group SI7501DN-T1 VISHAY</p>
 <p>SI7530DP-T1-E3 Vishay / Siliconix MOSFET N/P-CH 60V 3A PPAK SO-8</p>	 <p>SI7495DP-T1-GE3 Vishay / Siliconix MOSFET P-CH 12V 13A PPAK SO-8</p>	 <p>SI7501DN-T1-E3 Electro-Films (EFI) / Vishay MOSFET N/P-CH 30V 5.4A 1212-8</p>	 <p>SI7501DN-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N/P-CH 30V 5.4A 1212-8</p>

heiße Teile

Mehr

 SI7476DP-T1-GE3	 SI7478DP	 SI7478DP-T1-E3	 SI7478DP-T1-E3	 SI7478DP-T1-GE3
 SI7478DP-T1-GE3	 SI7483ADP	 SI7483ADP-T1-E3	 SI7483ADP-T1-E3	 SI7483ADP-T1-GE3
 SI7483ADP-T1-GE3	 SI7483DP-T1	 SI7483DP-T1-E3	 SI7483DP-T1-GE3	 SI7485DP-T1-E3
 SI7485DP-T1-E3	 SI7485DP-T1-GE3	 SI7485DP-T1-GE3	 SI7489DP	 SI7489DP-T1-GE3
 SI7489DP-T1-GE3	 SI7491DP	 SI7491DP-T1-GE3	 SI7491DP-T1-GE3	 SI7501DN-T1-E3
 SI7540ADP-T1-GE3	 SI7540ADP-T1-GE3	 SI7540DP-T1-E3	 SI7540DP-T1-E3	 SI7540DP-T1-GE3
 SI7540DP-T1-GE3	 SI7606DN-T1-E3	 SI7606DN-T1-GE3	 SI7611DN-T1-GE3	 SI7611DN-T1-GE3
 SI7613DN-T1-GE3	 SI7613DN-T1-GE3	 SI7615ADN-T1-GE3	 SI7615ADN-T1-GE3	 SI7615DN
 SI7615DN-T1-E3	 SI7615DN-T1-GE3	 SI7615DN-T1-GE3	 SI7617DN-T1-GE3	 SI7617DN-T1-GE3
 SI7619DN-T1-GE3	 SI7619DN-T1-GE3	 SI7621DN-T1-GE3	 SI7621DN-T1-GE3	 SI7625DN-T1-GE3

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